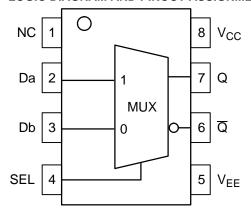
# **5V ECL 2:1 Multiplexer**

The MC10EL/100EL58 is a 2:1 multiplexer. The device is functionally equivalent to the E158 device with higher performance capabilities. With propagation delays and output transition times significantly faster than the E158, the EL58 is ideally suited for those applications which require the ultimate in AC performance.

The 100 Series contains temperature compensation.

- 230 ps Propagation Delay
- ESD Protection: > 1 KV HBM. > 100 V MM
- PECL Mode Operating Range:  $V_{CC}$ = 4.2 V to 5.7 V with  $V_{EE}$ = 0 V
- NECL Mode Operating Range:  $V_{CC}$ = 0 V with  $V_{EE}$ = -4.2 V to -5.7 V
- Internal Input Pulldown Resistors on D, D<sub>b</sub>, and SEL
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1
   For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 45 devices

## LOGIC DIAGRAM AND PINOUT ASSIGNMENT



## **PIN DESCRIPTION**

PIN	FUNCTION
Da, Db	ECL Data Inputs
$Q, \overline{Q}$	ECL Data Outputs
SEL	ECL Select Input
V <sub>CC</sub>	Positive Supply
V <sub>EE</sub>	Negative Supply
NC	No Connect

## **FUNCTION TABLE**

SEL*	Data
H	a
L	b

<sup>\*</sup> Pin will default low when left open.



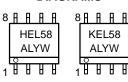
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## MARKING DIAGRAMS\*









TSSOP-8 DT SUFFIX CASE 948R





H = MC10 L = Wafer Lot K = MC100 Y = Year A = Assembly Location W = Work Week

## **ORDERING INFORMATION**

Device	Package	Shipping		
MC10EL58D	SO-8	98 Units/Rail		
MC10EL58DR2	SO-8	2500 Tape & Reel		
MC100EL58D	SO-8	98 Units/Rail		
MC100EL58DR2	SO-8	2500 Tape & Reel		
MC10EL58DT	TSSOP-8	98 Units/Rail		
MC10EL58DTR2	TSSOP-8	2500 Tape & Reel		
MC100EL58DT	TSSOP-8	98 Units/Rail		
MC100EL58DTR2	TSSOP-8	2500 Tape & Reel		

<sup>\*</sup>For additional information, see Application Note AND8002/D

## MAXIMUM RATINGS (Note 1.)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V <sub>CC</sub>	PECL Mode Power Supply	V <sub>EE</sub> = 0 V		8	V
V <sub>EE</sub>	NECL Mode Power Supply	V <sub>CC</sub> = 0 V		-8	V
V <sub>I</sub>	PECL Mode Input Voltage NECL Mode Input Voltage	V <sub>EE</sub> = 0 V V <sub>CC</sub> = 0 V	$ \begin{array}{c} V_{I} \leq V_{CC} \\ V_{I} \geq V_{EE} \end{array} $	6 -6	V
l <sub>out</sub>	Output Current	Continuous Surge		50 100	mA mA
TA	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			-65 to +150	°C
$\theta_{JA}$	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 SOIC 8 SOIC	190 130	°C/W °C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction to Case)	std bd	8 SOIC	41 to 44	°C/W
$\theta_{JA}$	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 TSSOP 8 TSSOP	185 140	°C/W °C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction to Case)	std bd	8 TSSOP	41 to 44	°C/W
T <sub>sol</sub>	Wave Solder	<2 to 3 sec @ 248°C		265	°C

<sup>1.</sup> Maximum Ratings are those values beyond which device damage may occur.

## 10EL SERIES PECL DC CHARACTERISTICS V<sub>CC</sub>= 5.0 V; V<sub>EE</sub>= 0.0 V (Note 1.)

•			–40°C			25°C	•		85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current		14	17		14	17		14	17	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 2.)	3920	4010	4110	4020	4105	4190	4090	4185	4280	mV
V <sub>OL</sub>	Output LOW Voltage (Note 2.)	3050	3200	3350	3050	3210	3370	3050	3227	3405	mV
V <sub>IH</sub>	Input HIGH Voltage	3770		4110	3870		4190	3940		4280	mV
V <sub>IL</sub>	Input LOW Voltage	3050		3500	3050		3520	3050		3555	mV
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.3			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 1. Input and output parameters vary 1:1 with  $V_{CC}$ .  $V_{EE}$  can vary +0.06 V / -0.5 V.
- 2. Outputs are terminated through a 50 ohm resistor to  $V_{CC}$ -2 volts.

# 10EL SERIES NECL DC CHARACTERISTICS $V_{CC}$ = 0.0 V; $V_{EE}$ = -5.0 V (Note 1.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current		14	17		14	17		14	17	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 2.)	-1080	-990	-890	-980	-895	-810	-910	-815	-720	mV
V <sub>OL</sub>	Output LOW Voltage (Note 2.)	-1950	-1800	-1650	-1950	-1790	-1630	-1950	-1773	-1595	mV
V <sub>IH</sub>	Input HIGH Voltage	-1230		-890	-1130		-810	-1060		-720	mV
V <sub>IL</sub>	Input LOW Voltage	-1950		-1500	-1950		-1480	-1950		-1445	mV
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.3			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 1. Input and output parameters vary 1:1 with V $_{CC}$ . V $_{EE}$  can vary +0.06 V / -0.5 V.
- 2. Outputs are terminated through a 50 ohm resistor to V<sub>CC</sub>-2 volts.

## 100EL SERIES PECL DC CHARACTERISTICS $V_{CC}$ = 5.0 V; $V_{EE}$ = 0.0 V (Note 1.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current		14	17		14	17		16	19	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 2.)	3915	3995	4120	3975	4045	4120	3975	4050	4120	mV
V <sub>OL</sub>	Output LOW Voltage (Note 2.)	3170	3305	3445	3190	3295	3380	3190	3295	3380	mV
V <sub>IH</sub>	Input HIGH Voltage	3835		4120	3835		4120	3835		4120	mV
V <sub>IL</sub>	Input LOW Voltage	3190		3525	3190		3525	3190		3525	mV
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 1. Input and output parameters vary 1:1 with  $V_{CC}$ .  $V_{EE}$  can vary +0.8 V / -0.5 V.
- 2. Outputs are terminated through a 50 ohm resistor to  $V_{CC}$ -2 volts.

# 100EL SERIES NECL DC CHARACTERISTICS $V_{CC}$ = 0.0 V; $V_{EE}$ = -5.0 V (Note 1.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current		14	17		14	17		16	19	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 2.)	-1085	-1005	-880	-1025	-955	-880	-1025	-955	-880	mV
V <sub>OL</sub>	Output LOW Voltage (Note 2.)	-1830	-1695	-1555	-1810	-1705	-1620	-1810	-1705	-1620	mV
V <sub>IH</sub>	Input HIGH Voltage	-1165		-880	-1165		-880	-1165		-880	mV
V <sub>IL</sub>	Input LOW Voltage	-1810		-1475	-1810		-1475	-1810		-1475	mV
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 1. Input and output parameters vary 1:1 with  $V_{CC}$ .  $\dot{V}_{EE}$  can vary +0.8 V / -0.5 V.
- 2. Outputs are terminated through a 50 ohm resistor to V<sub>CC</sub>-2 volts.

## AC CHARACTERISTICS $V_{CC}$ = 5.0 V; $V_{EE}$ = 0.0 V or $V_{CC}$ = 0.0 V; $V_{EE}$ = -5.0 V (Note 1.)

				–40°C			25°C			85°C		
Symbol	Characteris	tic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f <sub>max</sub>	Maximum Toggle Freque	ncy		TBD			TBD			TBD		GHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay to Output	D to Q SEL to Q	60 90	220 250	380 410	120 150	230 260	340 370	140 170	250 280	360 390	ps
t <sub>JITTER</sub>	Cycle-to-Cycle Jitter			TBD			TBD			TBD		ps
t <sub>r</sub> t <sub>f</sub>	Output Rise/Fall Times C (20% – 80%)	)	100	225	350	100	225	350	100	225	350	ps

1. 10 Series:  $V_{EE}$  can vary +0.06 V / -0.5 V. 100 Series:  $V_{EE}$  can vary +0.8 V / -0.5 V.

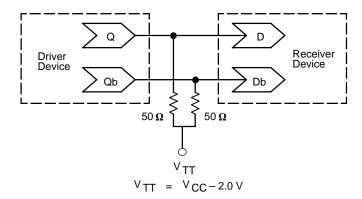


Figure 1. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020 – Termination of ECL Logic Devices.)

# **Resource Reference of Application Notes**

AN1404 – ECLinPS Circuit Performance at Non–Standard V<sub>IH</sub> Levels

AN1405 – ECL Clock Distribution Techniques

AN1406 – Designing with PECL (ECL at +5.0 V)

AN1503 - ECLinPS I/O SPICE Modeling Kit

AN1504 – Metastability and the ECLinPS Family

AN1560 \_ Low Voltage ECLinPS SPICE Modeling Kit

AN1568 - Interfacing Between LVDS and ECL

AN1596 - ECLinPS Lite Translator ELT Family SPICE I/O Model Kit

AN1650 – Using Wire-OR Ties in ECLinPS Designs

AN1672 – The ECL Translator Guide

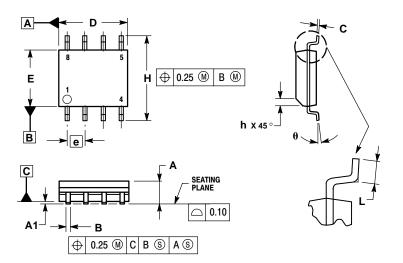
AND8001 - Odd Number Counters Design

AND8002 - Marking and Date Codes

AND8020 - Termination of ECL Logic Devices

# **PACKAGE DIMENSIONS**

## SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-06 ISSUE T

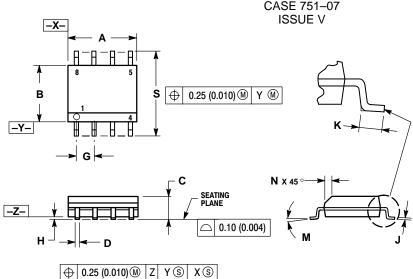


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. DIMENSIONS ARE IN MILLIMETER.
  3. DIMENSION DAND E DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
  5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS				
DIM	MIN	MAX				
Α	1.35	1.75				
A1	0.10	0.25				
В	0.35	0.49				
С	0.19	0.25				
D	4.80	5.00				
E	3.80	4.00				
е	1.27	BSC				
Н	5.80	6.20				
h	0.25	0.50				
L	0.40	1.25				
θ	0°	7°				

# **PACKAGE DIMENSIONS**

# SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-07



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- 4. MAXIMUM MOLD PHOTHOSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES				
DIM	MIN	MAX	MIN	MAX			
Α	4.80	5.00	0.189	0.197			
В	3.80	4.00	0.150	0.157			
С	1.35	1.75	0.053	0.069			
D	0.33	0.51	0.013	0.020			
G	1.27	7 BSC	0.050 BSC				
Н	0.10	0.25	0.004	0.010			
J	0.19	0.25	0.007	0.010			
K	0.40	1.27	0.016	0.050			
M	0 °	8 °	0 °	8 °			
N	0.25	0.50	0.010	0.020			
S	5.80	6.20	0.228	0.244			



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